R5426x SERIES

NO. EA-090-0504

OUTLINE

The R5426xxxxx Series are protection ICs for over-charge/discharge of rechargeable one-cell Lithium-ion (Li+) / Lithium polymer excess load current, further include a short circuit protector for preventing large external short circuit current and Excess charge/discharge-current.

Each of these ICs is composed of four voltage detectors, a reference unit, a delay circuit, a short circuit protector, an oscillator, a counter, and a logic circuit. When Over-charge voltage or Excess charge-current threshold crosses the each detector threshold from a low value to a high value, the output of C_{OUT} pin switches to low level after internal fixed delay time. After detecting over-charge or excess charge current, these detectors can be reset and the output of C_{OUT} becomes "H" when a kind of load is connected to V_{DD} after a charger is disconnected from the battery pack, and the cell voltage becomes lower than over-charge detector threshold. If a charger is continue to be connected to the battery pack, even the cell voltage becomes lower than over-charge detector threshold, over-charge state is not released.

The output of D_{OUT} pin, the output of Over-discharge detector and Excess discharge-current detector, switches to low level after internally fixed delay time, when discharged voltage crosses the detector threshold from a high value to a value lower than V_{DET2}.

After detecting over-discharge voltage, connect a charger to the battery pack, and when the battery supply voltage becomes higher than over-discharge detector threshold, VD2 is released and the voltage of D_{OUT} pin becomes "H" level.

An excess discharge-current and short circuit state can be sensed and cut off through the built in excess current detector, VD3, with D_{OUT} being enabled to low level. Once after detecting excess discharge-current or short circuit, the VD3 is released and D_{OUT} level switches to high by detaching a battery pack from a load system.

After detecting over-discharge, supply current will be kept extremely low by halting internal circuits' operation. By setting the DS pin at V_{DD} level, the output delay of all items except short circuit detector can be shortened. Especially, the delay time of over-charge detector can be reduced into approximately 1/90, therefore, testing time of protector circuit board can be reduced. Further, when the DS pin is set at the specified middle range voltage, output delay circuit is disabled, then over-charge and over-charger current can be detected immediately. Output delay time would be less than several tens µs in this case. Output type of C_{OUT} and D_{OUT} are CMOS. 6-pin, SOT-23-6 or SON-6 are available.

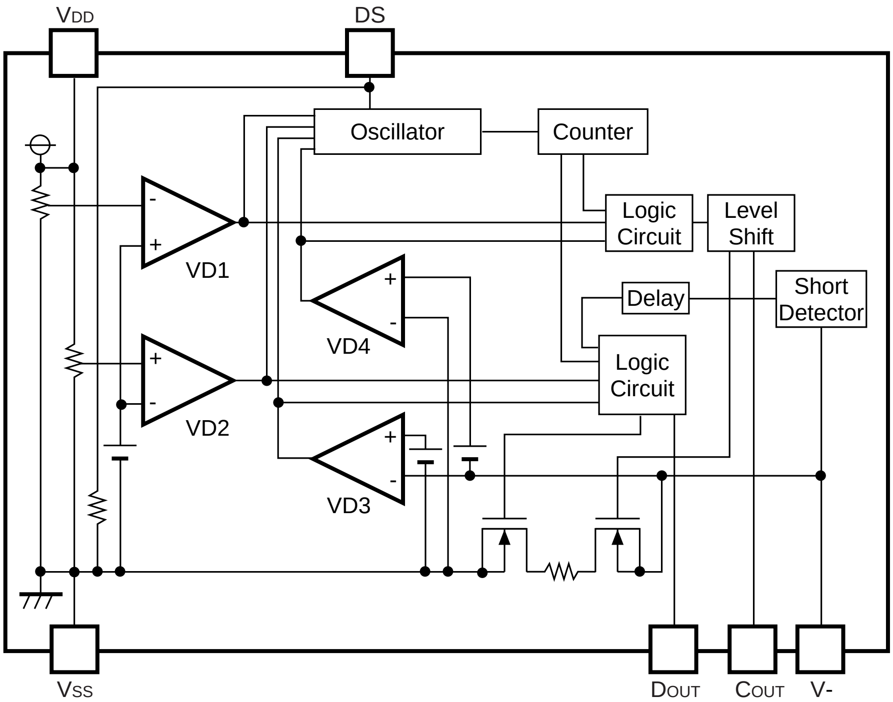
FEATURES

- Manufactured with High Voltage Tolerant Process...............Absolute Maximum Rating 28V
- Low supply current .... Supply current (At normal mode) Typ. 3.0μA
  Standby current (detecting over-discharge) Max. 0.1μA
- High accuracy detector threshold................. Over-charge detector (Topt=25°C) ±25mV
  (Topt=-5 to 55°C) ±30mV
  Over-discharge detector ±2.5%
  Excess discharge-current detector ±20mV
  Excess charge-current detector ±30mV
- Variety of detector threshold......................Over-charge detector threshold 4.0V to 4.5V step of 0.005V
  Over-discharge detector threshold 2.0V to 3.0V step of 0.005V
  Excess discharge-current threshold 0.05V to 0.4V step of 0.005V
  Excess charge-current threshold Fixed at -0.1V
- Internal fixed Output delay time.................... Over-charge detector Output Delay 250ms/1s/5s
  (Select among the options) .... Over-discharge detector Output Delay 20ms
  Excess discharge-current detector Output Delay 6ms/12ms
  Short Circuit detector Output Delay 400μs
  Excess charge-current detector Output Delay 8ms/16ms/1s
- DS pin.. At V_{DD} level, Output Delay time of all items except short-circuit can be reduced. (Delay Time for over-charge becomes about 1/90 of normal state.) At the specified middle range level, delay circuit is disabled.
- 0V-battery charge option ....acceptable/unacceptable
- With Latch function after over-charge detect
- Ultra Small package ....SOT-23-6 / SON-6

APPLICATIONS

- Li+ / Li Polymer protector of over-charge, over-discharge, excess-current for battery pack
- High precision protectors for cell-phones and any other gadgets using on board Li+ / Li Polymer battery

BLOCK DIAGRAM



SELECTION GUIDE

In the R5426x Series four of the input threshold for over-charge, over-discharge, excess discharge current, and excess charge current detectors, package type can be designated.

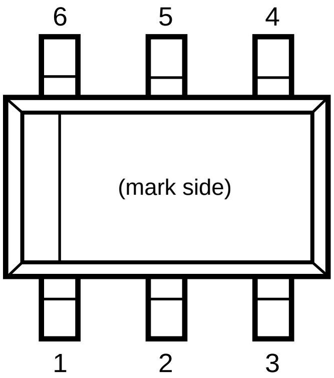
Part Number is designated as follows:

R5426xxxxxx-xx ←Part Number
↑ ↑ ↑↑ ↑
a b cd e

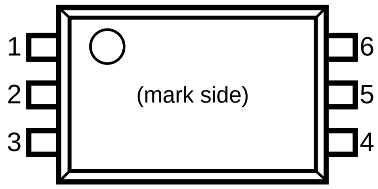
Code	Contents
a	Package Type N: SOT-23-6 D: SON6
b	Serial Number for the R5426 Series designating input four threshold for over-charge, over-discharge, excess discharge-current, and excess charge-current detectors.
c	Designation of Output delay option of over-charge, excess charge-current, and excess discharge-current.
d	Designation of version symbols
e	Taping Type: TR (refer to Taping Specification)

PIN CONFIGURATIONS

SOT-23-6



SON-6



PIN DESCRIPTION

Pin No		Symbol	Description
SOT-23-6	SON-6		
1	1	D_{OUT}	Output of over-discharge detection, CMOS output
2	6	V-	Pin for charger negative input
3	5	C_{OUT}	Output of over-charge detection, CMOS output
4	4	DS	Pin for reduce pre-set output delay time
5	2	V_{DD}	Power supply pin, the substrate voltage level of the IC.
6	3	V_{SS}	Ground pin for the IC

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V_{DD}	Supply voltage	-0.3 to 12	V
	Input Voltage		
V-	V- pin	V_{DD} -28 to V_{DD} +0.3	V
V_{DS}	DS pin	V_{SS} -0.3 to V_{DD} +0.3	V
	Output voltage		
VC_{OUT}	C_{OUT} pin	V_{DD} -28 to V_{DD} +0.3	V
VD_{OUT}	D_{OUT} pin	V_{SS} -0.3 to V_{DD} +0.3	V
P_D	Power dissipation	150	mW
Topt	Operating temperature range	-40 to 85	°C
Tstg	Storage temperature range	-55 to 125	°C

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum ratings are threshold limit values that must not be exceeded ever for an instant under any conditions. Moreover, such values for any two items must not be reached simultaneously. Operation above these absolute maximum ratings may cause degradation or permanent damage to the device. These are stress ratings only and do not necessarily imply functional operation below these limits.

ELECTRICAL CHARACTERISTICS

Unless otherwise specified, Topt=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{DD1}	Operating input voltage	Voltage defined as V_{DD}-V_{SS}	1.5		5.0	V
Vst	Minimum operating Voltagefor 0V charging *Note 1	Voltage defined as V_{DD}-V- V_{DD}-V_{SS}=0V			1.5	V
Vnochg	Maximum Battery Voltage level of low voltage battery charge inhibitory circuit *Note 2	Voltage defined as V_{DD}-V_{SS} V_{DD}-V-=4V	0.6	1.0	1.4	V
V_{DET1}	Over-charge threshold	Detect rising edge of supply voltage R1=330Ω R1=330Ω (Topt=-5 to 55°C) *Note3	V_{DET1}-0.025 V_{DET1}-0.030	V_{DET1} V_{DET1}	V_{DET1}+0.025 V_{DET1}+0.030	V V
tV_{DET1}	Output delay of over-charge	V_{DD}=3.6V to 4.4V	tV_{DET1}×0.7	tV_{DET1}	tV_{DET1}×1.3	s
tV_{REL1}	Output delay of release from over-charge	V_{DD}=4V, V-=0V to 1V	11	16	21	ms
V_{DET2}	Over-discharge threshold	Detect falling edge of supply voltage	V_{DET2} ×0.975	V_{DET2}	V_{DET2} ×1.025	V
tV_{DET2}	Output delay of over-discharge	V_{DD}=3.6V to 2.2V	14	20	26	ms
tV_{REL2}	Output delay of release from over-discharge	V_{DD}=3V V-=3V to 0V	0.7	1.2	1.7	ms
V_{DET3}	Excess discharge-current threshold	Detect rising edge of ‘V-‘ pin voltage	V_{DET3} +0.020	V_{DET3}	V_{DET3} +0.020	V
tV_{DET3}	Output delay of excess discharge-current	V_{DD}=3.0V,V-=01V to 1V 6ms type 12ms type	4 8	6 12	8 16	ms
tV_{REL3}	Output delay of release from excess discharge-current	V_{DD}=3.0V, V-=3V to 0V	0.7	1.2	1.7	ms
V_{DET4}	Excess charge-current threshold	Detect falling edge of 'V-' pin voltage	-0.13	-0.10	-0.07	V
tV_{DET4}	Output delay of excess charge-current	V_{DD}=3.0V V-=0V to -1V 8ms type 16ms type 1000ms type	5 11 700	8 16 1000	11 21 1300	ms
tV_{REL4}	Output delay of release from excess charge-current	V_{DD}=3.0V, V-=-1V to 0V	0.7	1.2	1.7	ms
Vshort	Short protection voltage	V_{DD}=3.0V	V_{DD}-1.4	V_{DD}-1.1	V_{DD}-0.8	mA
Tshort	Output Delay of Short protection	V_{DD}=3.0V, V-=0V to 3V	250	400	600	µs
Rshort	Reset resistance for Excess discharge-Current protection	V_{DD}=3.6V, V-=1V	15	30	45	kΩ
V_{IH}	DS pin "H" input voltage		V_{DD}-0.5		V_{DD}+0.3	V
V_{IM}	DS pin "M" input voltage	V_{DD}=3.6V to 4.4V	1.2		V_{DD}-1.1	V

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
R_{DS}	DS pin pull-down resistance	V_{DD}=3.6V	0.5	1.3	2.5	MΩ
V_{OL1}	Nch ON voltage of C_{OUT}	Iol=50µA, V_{DD}=4.5V		0.4	0.5	V
V_{OH1}	Pch ON voltage of C_{OUT}	Ioh=-50µA, V_{DD}=3.9V	3.4	3.7		V
V_{OL2}	Nch ON voltage of D_{OUT}	Iol=50µA, V_{DD}=2.0V		0.2	0.5	V
V_{OH2}	Pch ON voltage of D_{OUT}	Ioh=-50µA, V_{DD}=3.9V	3.4	3.7		V
I_{DD}	Supply current	V_{DD}=3.9V, V- =0V		3.0	6.0	µA
I_S	Standby current	V_{DD}=2.0V			0.1	µA

∗Note1: Specified for A version
∗Note2: Specified for B version
∗Note3: We compensate for this characteristic related to temperature by laser-trim, however, this specification is guaranteed by design, not production tested.

OPERATION

- **VD1 / Over-Charge Detector**

The VD1 monitors V_{DD} pin voltage while charge the battery pack. When the V_{DD} voltage crosses over-charge detector threshold V_{DET1} from a low value to a value higher than the V_{DET1}, the VD1 can sense a over-charging and an external charge control Nch MOSFET turns off with C_{OUT} pin being at "L" level.

To reset the VD1 making the C_{OUT} pin level to "H" again after detecting over-charge, in such conditions that a time when the V_{DD} voltage is down to a level lower than over-charge voltage.

Connecting a kind of loading to V_{DD} after disconnecting a charger from the battery pack when the V_{DD} voltage is lower than Over-charge detector threshold, VD1 can be reset. Output voltage of C_{OUT} pin becomes "H", and it makes an external Nch MOSFET turn on, and charge cycle is available. In other words, once over-charge is detected, even the supply voltage becomes low enough, if a charger is continue to be connected to the battery pack, recharge is not possible. Therefore this over-charge detector has no hysteresis. To judge whether or not load is connected, Excess-discharge current detector is used. In other words, by connecting some load, V- pin voltage becomes equal or more than Excess-discharge current detector threshold, and reset Over-charge detecting state.

After detecting over-charge with the V_{DD} voltage of higher than V_{DET1}, connecting system load to the battery pack makes load current allowable through parasitic diode of external charge control FET.

The C_{OUT} level would be "H" when the V_{DD} level is down to a level below the V_{DET1} by continuous drawing of load current.

Internal fixed output delay times for over-charge detection and release from over-charge exist. Even when the V_{DD} level becomes a higher level than V_{DET1} if the V_{DD} voltage would be back to a level lower than the VDET1 within a time period of the output delay time, VD1 would not output a signal for turning off the charge control FET. Besides, after detecting over-charge, while the V_{DD} is lower than over-charge detector, even if a charger is removed and connected a load, when the voltage is recovered within output delay time of release from over-charge, over-charge state is not released.

A level shifter incorporated in a buffer driver for the C_{OUT} pin makes the "L" level of C_{OUT} pin to the V - pin voltage and the "H" level of C_{OUT} pin is set to V_{DD} voltage with CMOS buffer.

• VD2 / Over-Discharge Detector

The VD2 is monitoring a V_{DD} pin voltage. When the V_{DD} voltage crosses the over-discharge detector threshold V_{DET2} from a high value to a value lower than the V_{DET2}, the VD2 can sense an over-discharging and the external discharge control Nch MOSFET turns off with the D_{OUT} pin being at "L" level.

To reset the VD2 with the D_{OUT} pin level being "H" again after detecting over discharge, it is necessary to connect a charger to the battery pack. When the V_{DD} voltage stays under over-discharge detector threshold V_{DET2}, charge-current can flow through parasitic diode of an external discharge control MOSFET, then after the V_{DD} voltage comes up to a value larger than V_{DET2}, then, D_{OUT} becomes "H" and discharging process would be able to advance through ON state MOSFET for discharge control.

Connecting a charger to the battery pack makes the D_{OUT} level being "H" instantaneously when the V_{DD} voltage is higher than V_{DET2}.

- When a cell voltage equals to zero, operation varies and depends on the mask version.

A version: the voltage of a charger is equal or more than 0V-charge minimum voltage (Vst), C_{OUT} pin becomes "H" and system allowable to charge

B Version: when the V_{DD} pin voltage is equal or lower than charge inhibitory maximum voltage (Vnochg), even a charger is connected to a battery pack, C_{OUT} pin is stacked at "L" and charge current cannot flow.

An output delay time for over-discharge detection is fixed internally. When the V_{DD} level is down to a lower level than V_{DET2} if the V_{DD} voltage would be back to a level higher than the V_{DET2} within a time period of the output delay time, VD2 would not output a signal for turning off the discharge control FET. Output delay time for release from over-discharge is also set typically at 1.2ms.

After detecting of over-discharge by VD2, supply current would be reduced to maximum 0.1µA at V_{DD}=2.0V and be into standby by halting all circuits and consumption current of IC itself is minimized.

The output type of D_{OUT} pin is CMOS having "H" level of V_{DD} and "L" level of V_{SS}.

• VD3 /Excess discharge-current Detector, Short Circuit Protector

Both of the excess current detector and short circuit protection can work when the both of control FETs are in "ON" state.

When the V- pin voltage is up to a value between the short protection voltage Vshort (Typically V_{DD}-1.1V) and excess discharge-current threshold V_{DET3}, VD3 operates and further soaring of V- pin voltage higher than Vshort makes the short circuit protector enabled. This leads the external discharge control Nch MOSFET turns off with the D_{OUT} pin being at "L" level.

An output delay time for the excess discharge-current detector is internally fixed.

A quick recovery of V- pin level from a value between Vshort and V_{DET3} within the delay time keeps the discharge control FET staying "H" state. Output delay time for Release from excess discharge-current detection is also set at typically 1.2ms.

When the short circuit protector is enabled, the D_{OUT} would be "L" and its delay time would be typically 400µs.

The V - pin has a built-in pulled down resistor, typically 30kW, with connecting to the V_{SS} pin.

After an excess discharge-current or short circuit protection is detected, removing a cause of excess discharge-current or external short circuit makes an external discharge control FET to an "ON" state automatically with the V- pin level being down to the V_{SS} level through built-in pulled down resistor. The reset resistor of excess discharge-current is off at normal state. Only when detecting excess discharge-current or short circuit, the resistor is on.

Output delay time of excess discharge-current is set shorter than the delay time for over-discharge detector. Therefore, if V_{DD} voltage would be lower than V_{DET2} at the same time as the excess discharge-current is detected, the R5426xxxxxx is at excess discharge-current detection mode. By disconnecting a load, VD3 is automatically released from excess discharge-current.

• VD4/ Excess charge-current detector

When the battery pack is chargeable and discharge is also possible, VD4 senses V- pin voltage. For example, if the battery pack is charged with an inappropriate charger, excess current flows, then the voltage of V- pin becomes equal or less than excess charge-current detector threshold. Then, the output of C_{OUT} becomes "L", and prevents from flowing excess current in the circuit by turning off the external Nch MOSFET.

Output delay of excess charge current is internally fixed. Even the voltage level of V- pin becomes equal or lower than excess charge-current detector threshold, the voltage is higher than the VD4 threshold within the delay time, excess-charge current state is not detected.

VD4 can be released with disconnecting a charger and setting a load.

• DS (Delay Shorten) function

Output delay time of over-charge, over-discharge, excess discharge-current, excess charge-current, and release from those detecting modes can be shorter than those setting value by forcing V_{DD} voltage to DS pin.

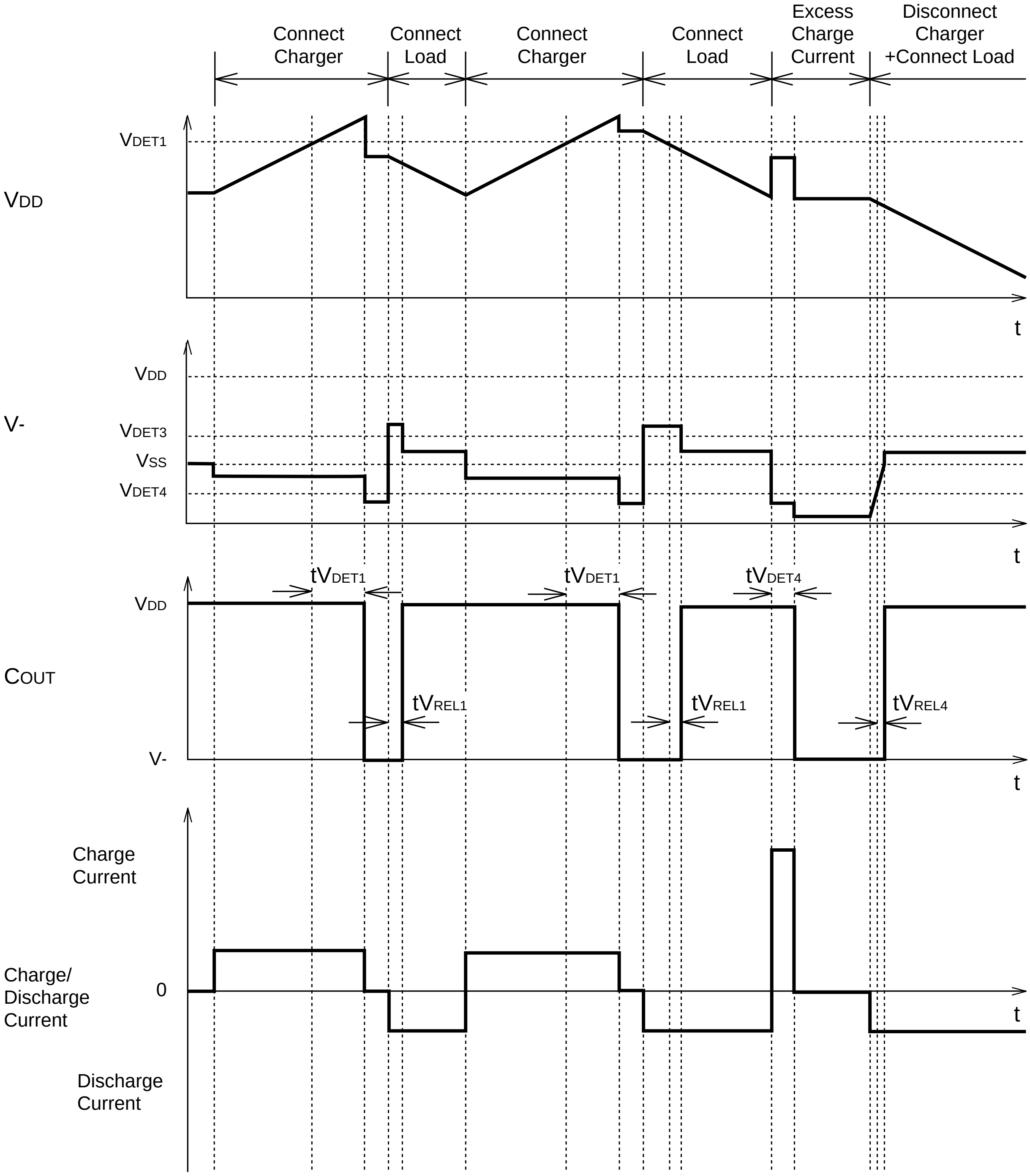
By forcing the specified middle range voltage to DS pin, Output Delay Circuit can be disabled. Therefore, under this condition, when over-charge or excess charge current is detected, output level can be checked without delay.

1.3MΩ pull-down resistor is connected between DS pin and V_{SS} internally.

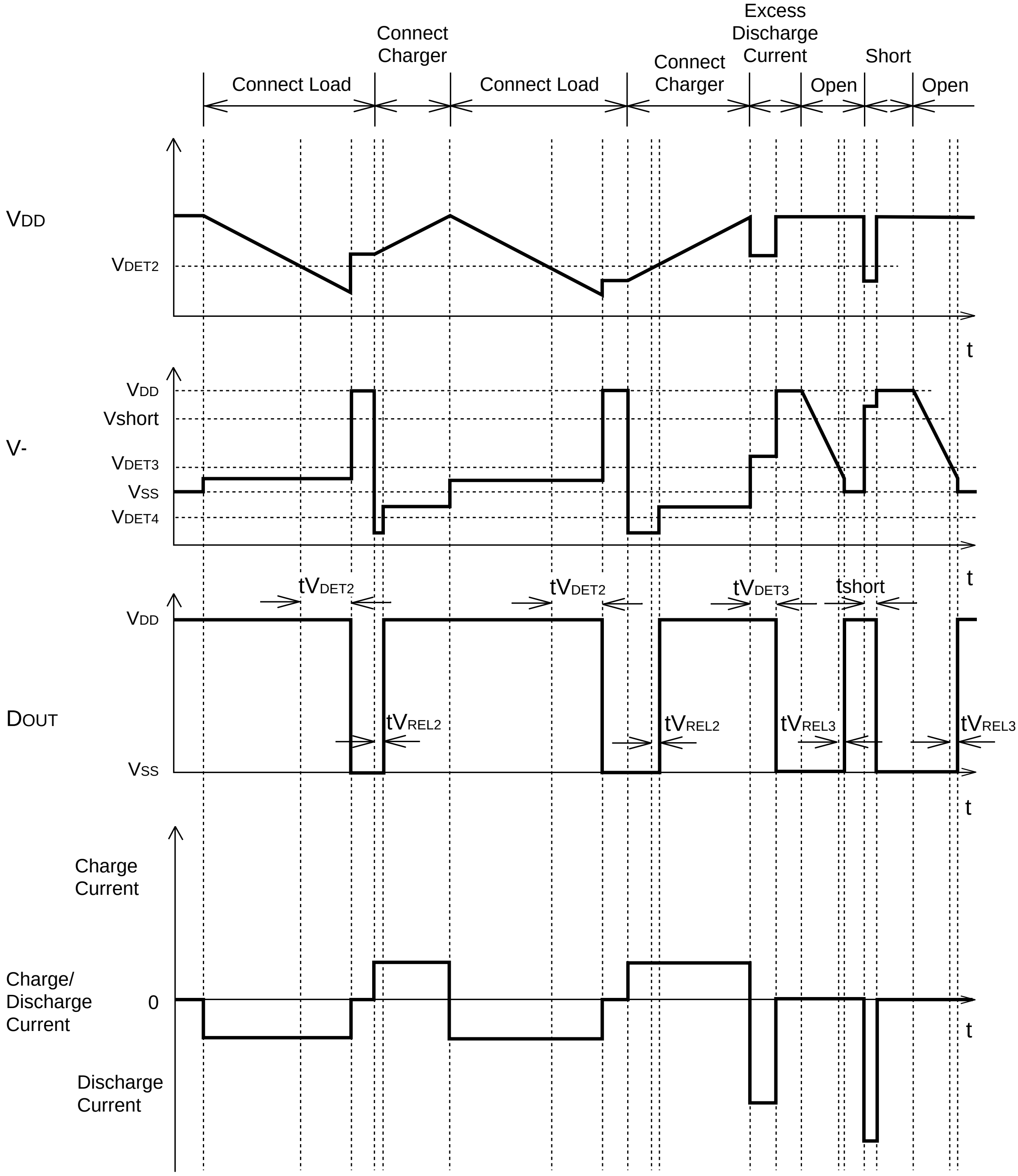
At the normal operation, DS pin should be at no connection state.

TIMING CHART

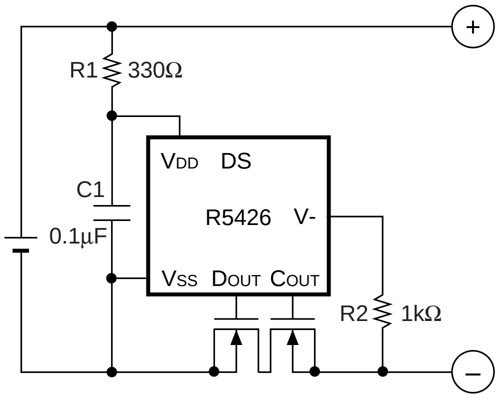
1. Over-charge, Excess charge Current Operation



2. Over discharge, Excess discharge current, Short circuit operation



TYPICAL APPLICATION



APPLICATION HINTS

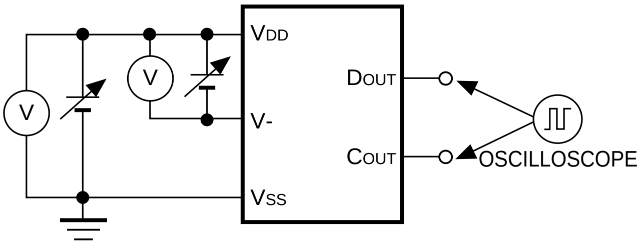
R1 and C1 will stabilize a supply voltage to the R5426xxxxxx. A recommended R1 value is less than 1kΩ.

A larger value of R1 leads higher detection voltage, makes some errors, because of shoot through current flown in the R5426xxxxxx.

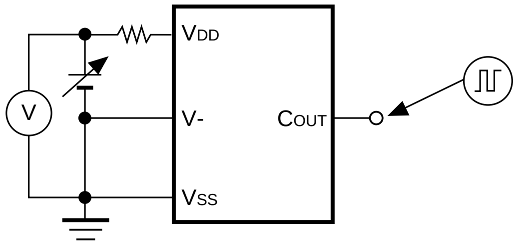
R1 and R2 can operate also as parts for current limit circuit against reverse charge or applying a charger with excess charging voltage to the R5426xxxxxx, battery pack. Small value of R1 and R2 may cause over-power consumption rating of power dissipation of the R5426xxxxx. Therefore, total value of 'R1+R2' should be equal or more than 1kΩ.

On the other hand, if large value of R2 is set, release from over-discharge by connecting a charger might not be possible. Recommended R2 value is equal or less than 30kΩ.

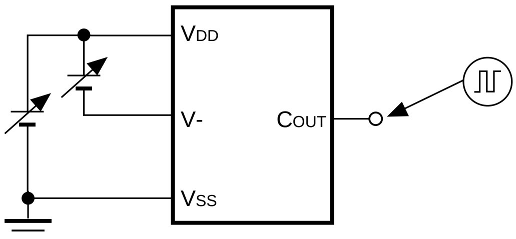
TEST CIRCUITS



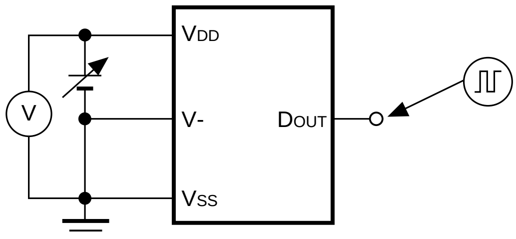
A



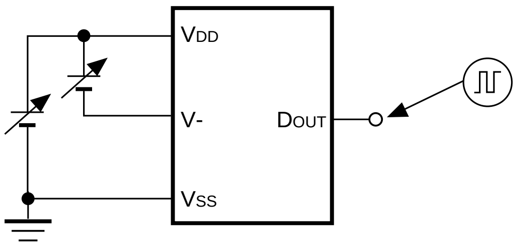
B



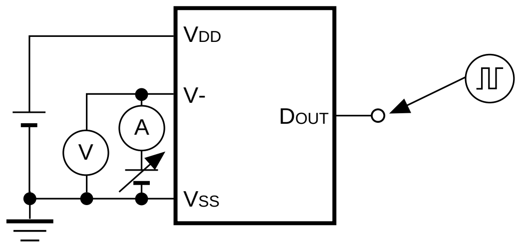
C



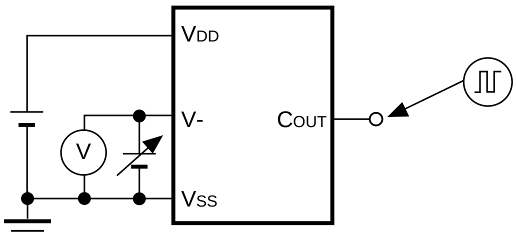
D



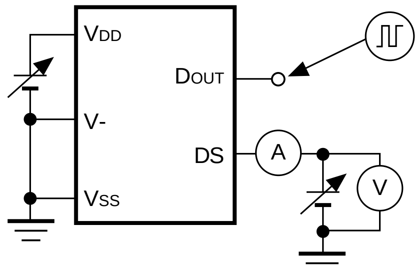
E



F



G



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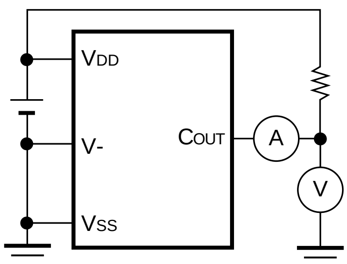
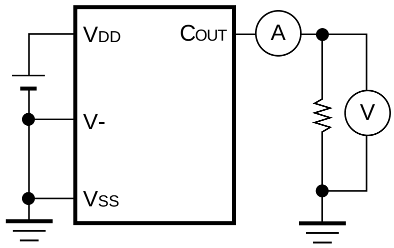
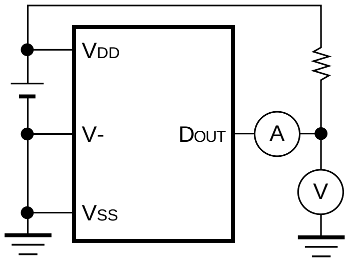


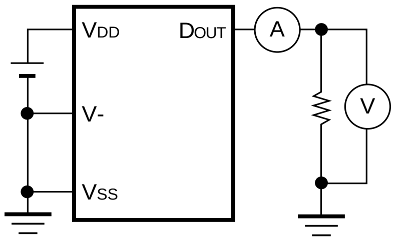
I



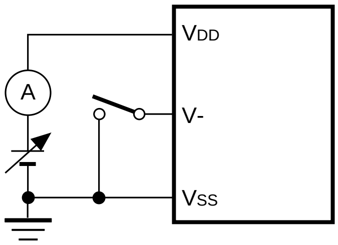
J



K



L



M

Typical Characteristics were obtained with using those above circuits:

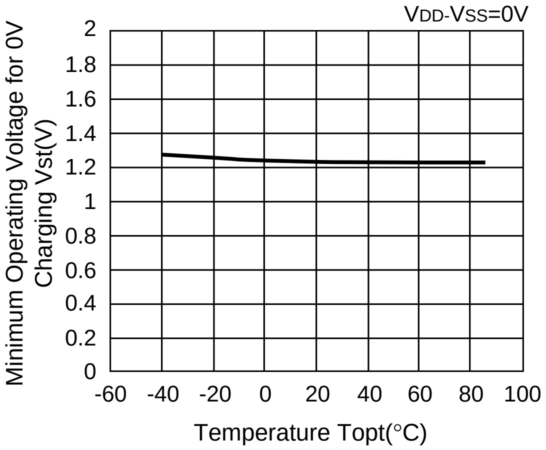
Test Circuit A:	Typical characteristics 1) 2)
Test Circuit B:	Typical characteristics 3) 4)
Test Circuit C:	Typical characteristics 5)
Test Circuit D:	Typical characteristics 6) 7)
Test Circuit E:	Typical characteristics 8)
Test Circuit F:	Typical characteristics 9) 10) 11) 12) 13) 14)
Test Circuit G:	Typical characteristics 15) 16) 17)
Test Circuit H:	Typical characteristics 18) 19) 20)
Test Circuit I:	Typical characteristics 21)
Test Circuit J:	Typical characteristics 22)
Test Circuit K:	Typical characteristics 23)
Test Circuit L:	Typical characteristics 24)
Test Circuit M:	Typical characteristics 25) 26)

TYPICAL CHARACTERISTICS

Part1

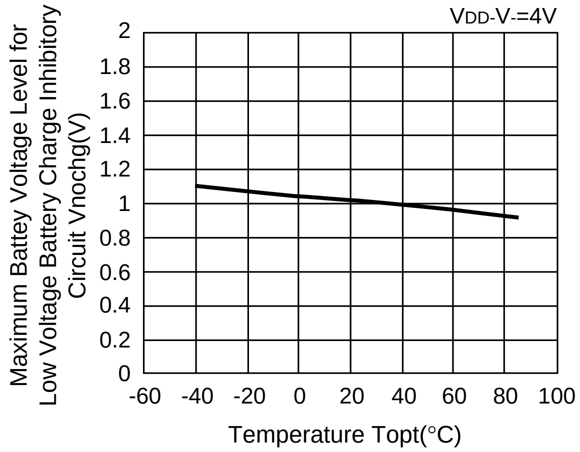
1) Minimum Operating Voltage for 0V Cell Charging vs. Temperature

R5426x102CA



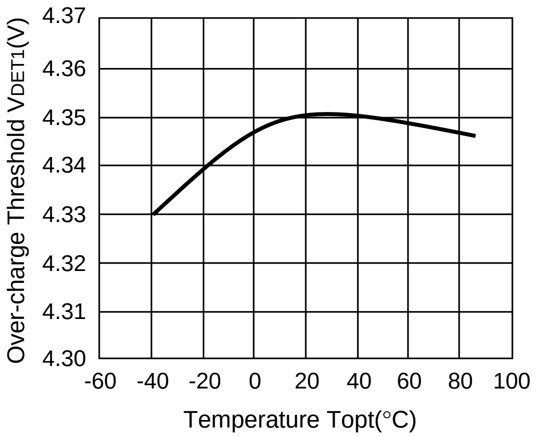
2) Maximum Battery Voltage Level for Low Voltage Battery Charge Inhibitory Circuit vs. Temperature

R5426x104BB



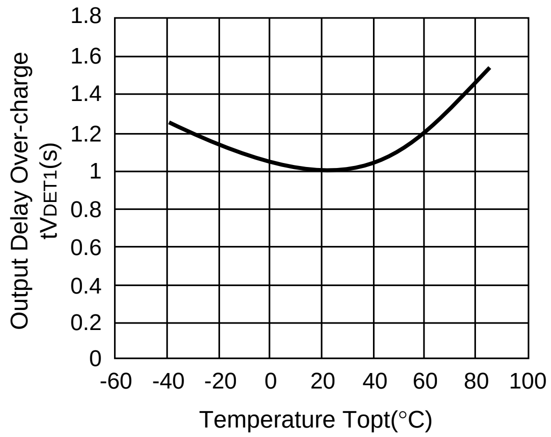
3) Over-Charge Threshold vs. Temperature

R5426x102CA



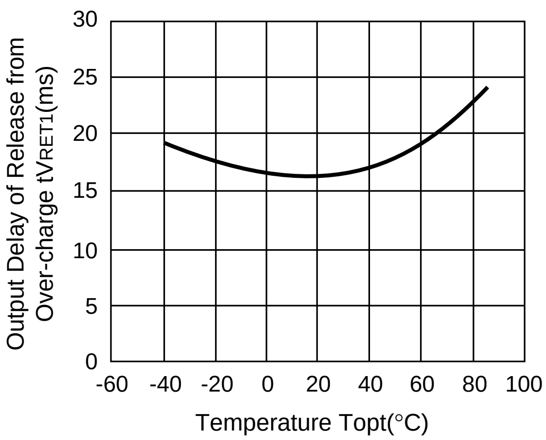
4) Output Delay of Over-charge vs. Temperature

R5426x102CA



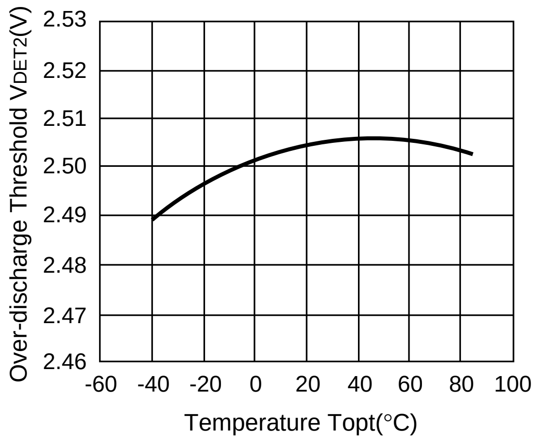
5) Output Delay of Release from Over-charge vs. Temperature

R5426x102CA

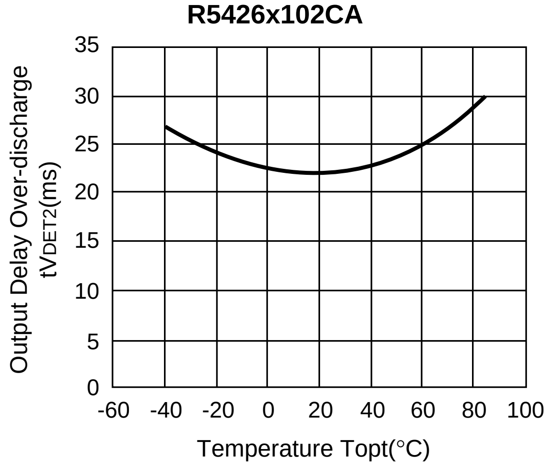


6) Over discharge Threshold vs. Temperature

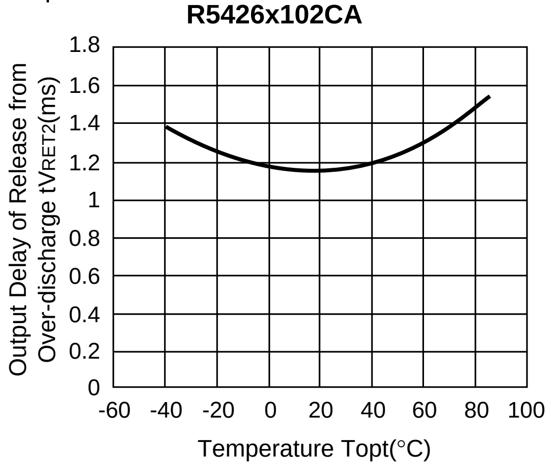
R5426x102CA



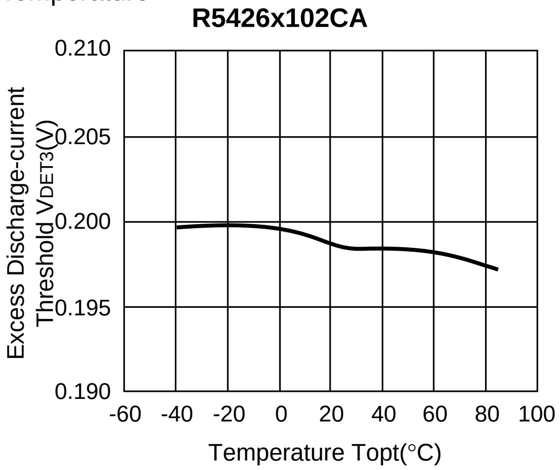
7) Output Delay of Over-discharge vs. Temperature



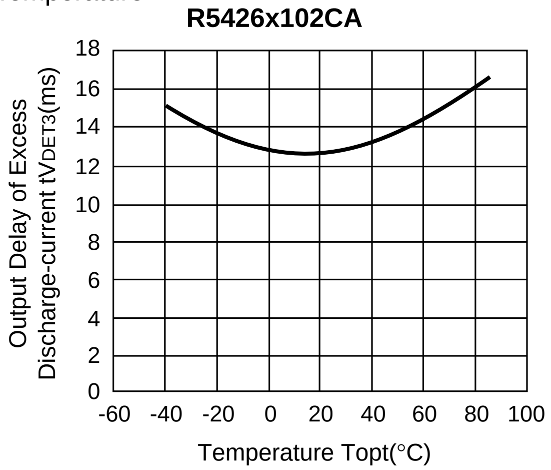
8) Output Delay of Release from Over-discharge vs. Temperature



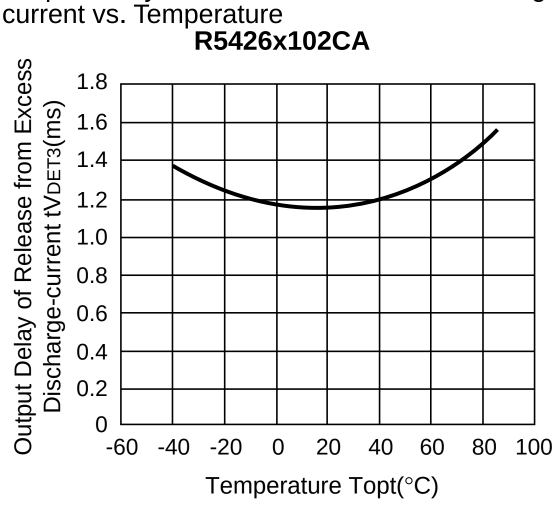
9) Excess Discharge-current Threshold vs. Temperature



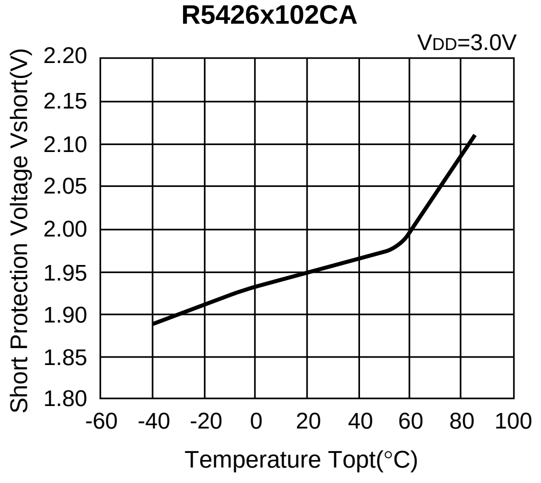
10) Output Delay of Excess Discharge-current vs. Temperature



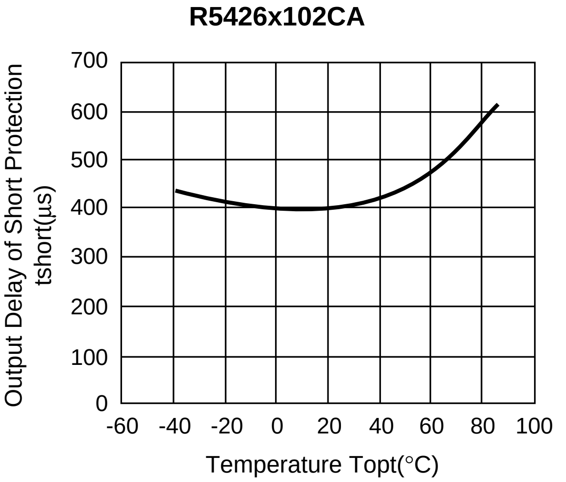
11) Output Delay of Release from Excess Dicharge-current vs. Temperature



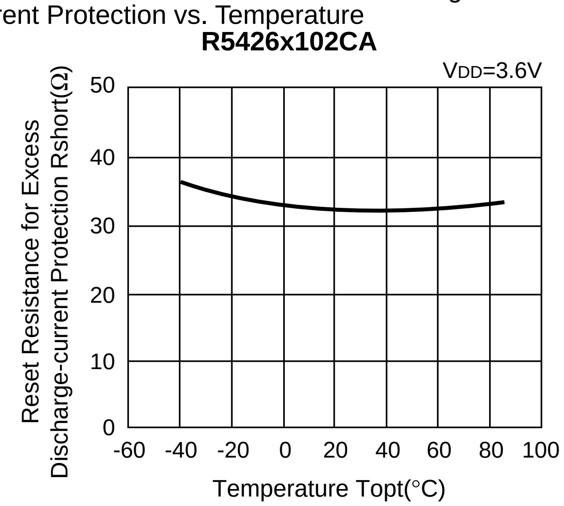
12) Short Protection Voltage vs. Temperature



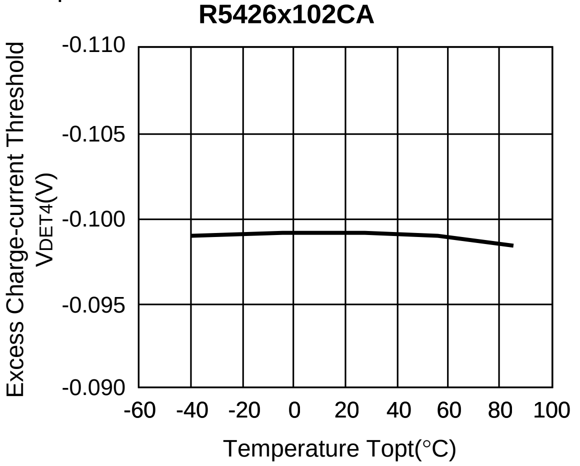
13) Output Delay of Short Protection vs. Temperature



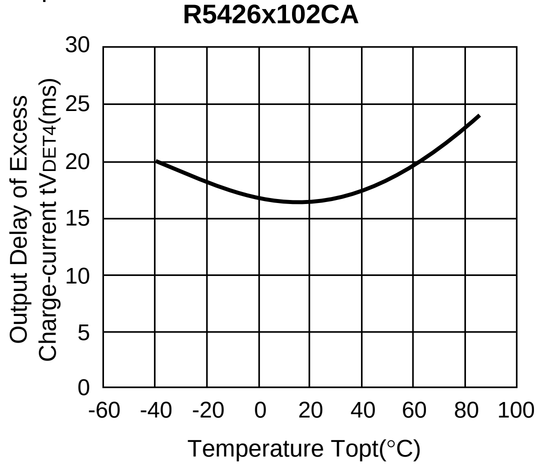
14) Reset Resistance for Excess Discharge current Protection vs. Temperature



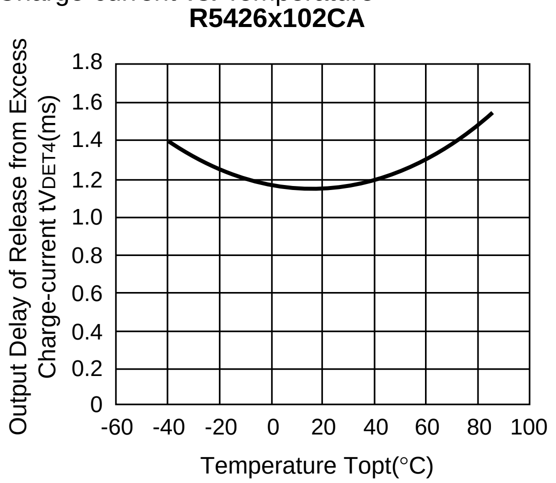
15) Excess Charge-current Threshold vs. Temperature



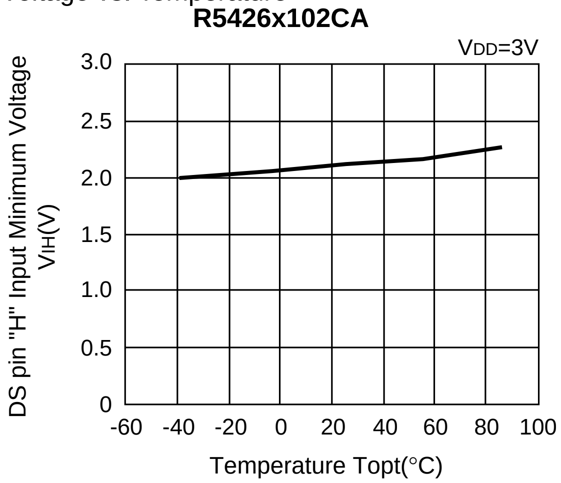
16) Output Delay of Excess Charge-current vs. Temperature



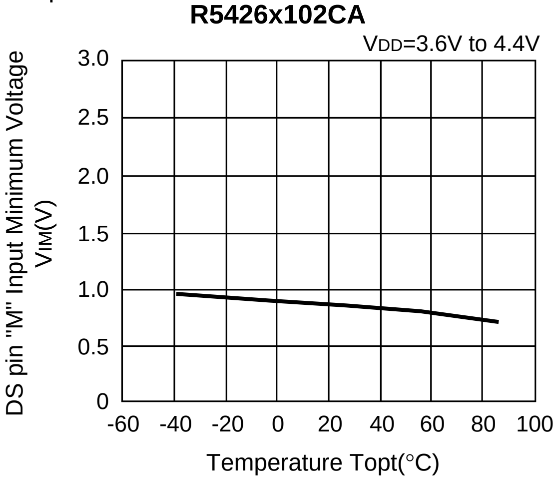
17) Output Delay of Release from Excess Charge-current vs. Temperature



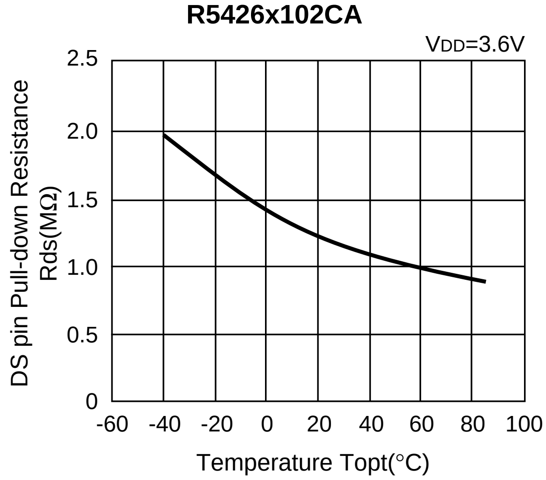
18) DS pin “H” Input Minimum Voltage vs. Temperature



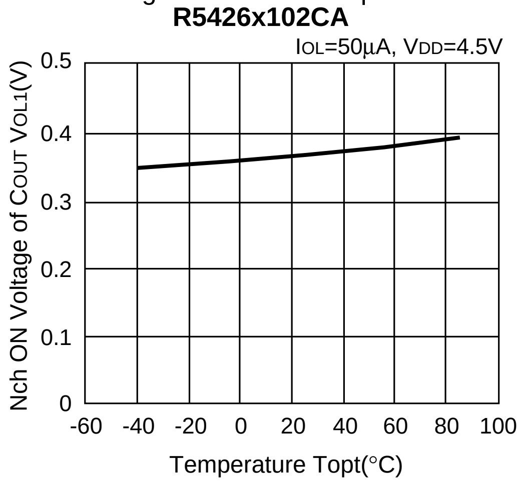
19) DS pin "M" Input Minimum Voltage vs. Temperature



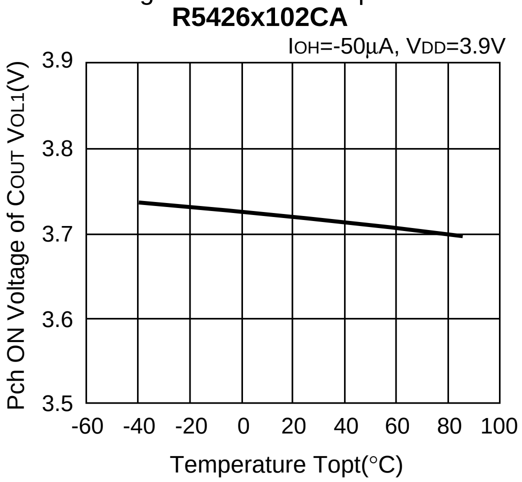
20) DS pin Pull-down Resistance vs. Temperature



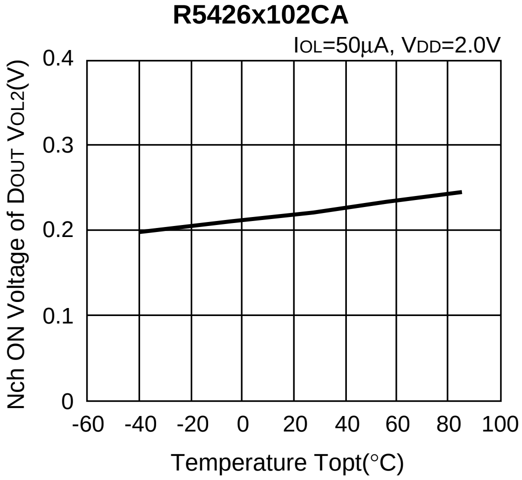
21) Nch ON Voltage of COUT vs. Temperature



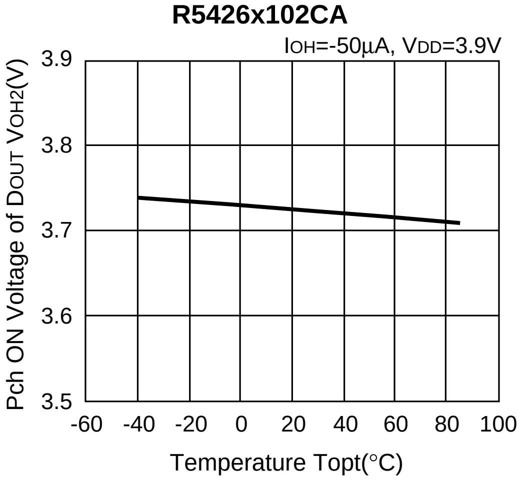
22) Pch ON Voltage of COUT vs. Temperature



23) Nch ON Voltage of DOUT vs. Temperature

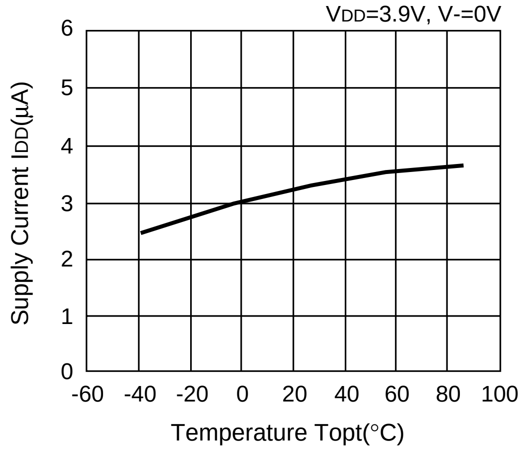


24) Pch ON Voltage of DOUT vs. Temperature



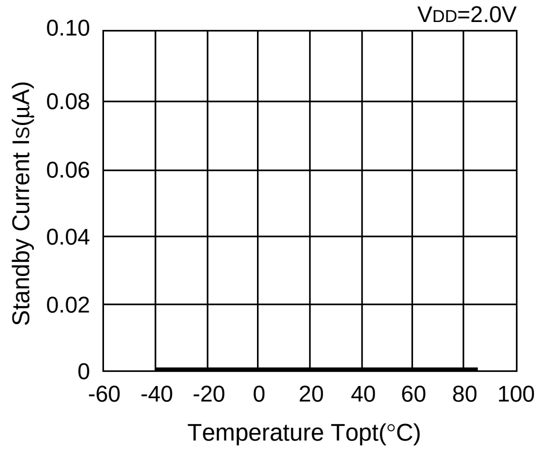
25) Supply Current vs. Temperature

R5426x102CA



26) Standby Current vs. Temperature

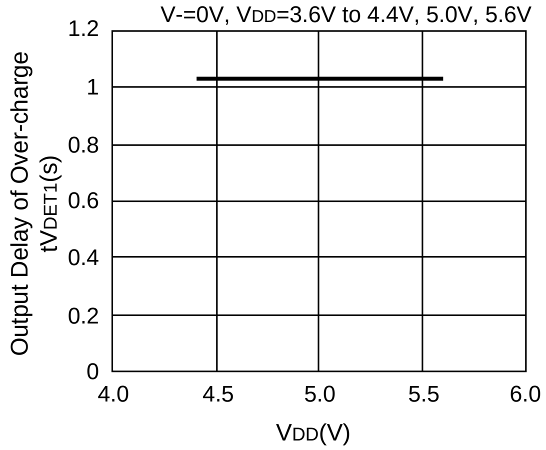
R5426x102CA



Part 2 Delay Time dependence on V_{DD}

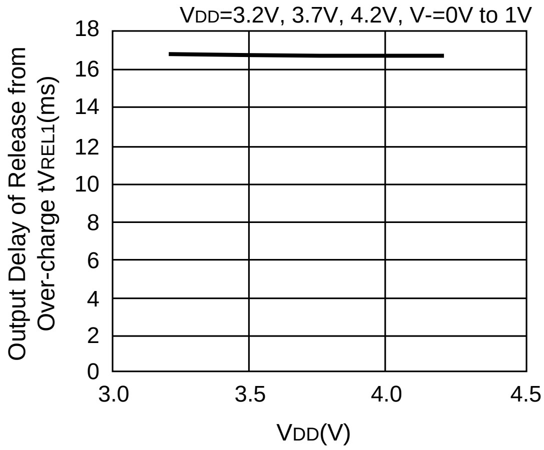
1) Delay Time for Over-charge detect vs. V_{DD}

R5426x113CA



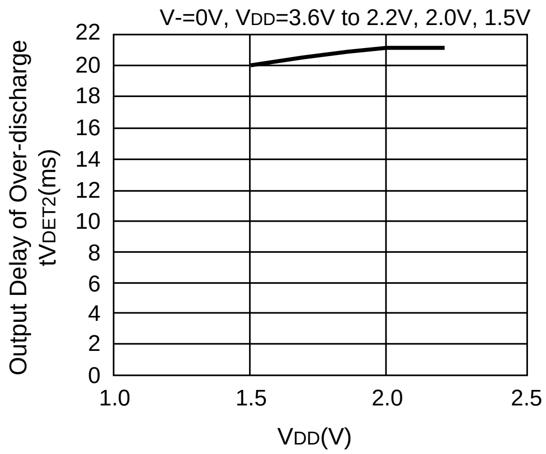
2) Delay Time for Release from Over-charge vs. V_{DD}

R5426x113CA



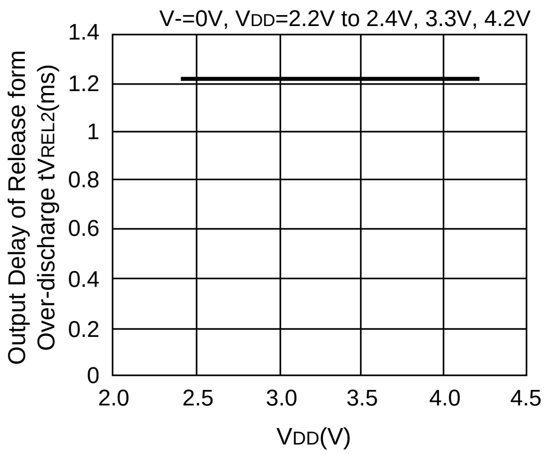
3) Output Delay of Over-discharge detect vs. V_{DD}

R5426x113CA



4) Output Delay for Release from Over-discharge vs. V_{DD}

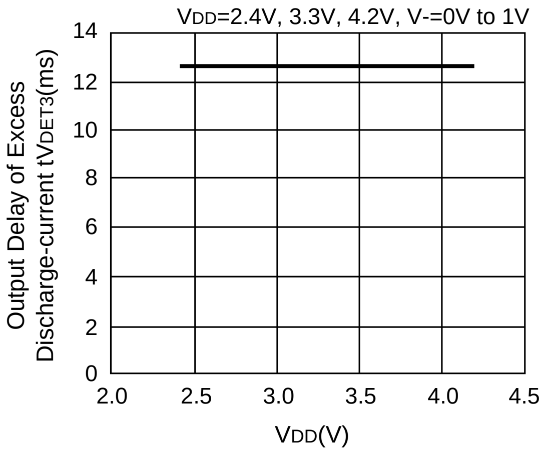
R5426x113CA



RICOH

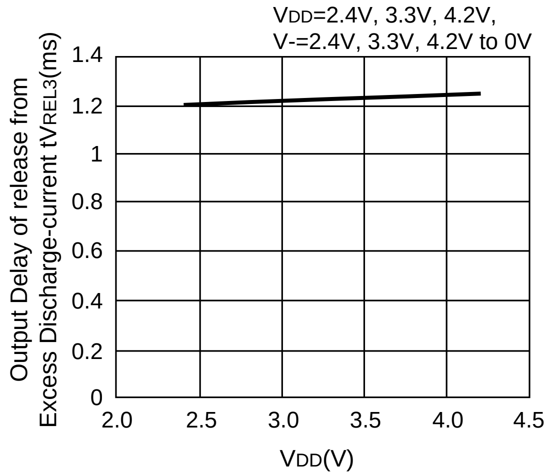
5) Output Delay for Excess Current during Discharge vs. V_{DD}

R5426x113CA



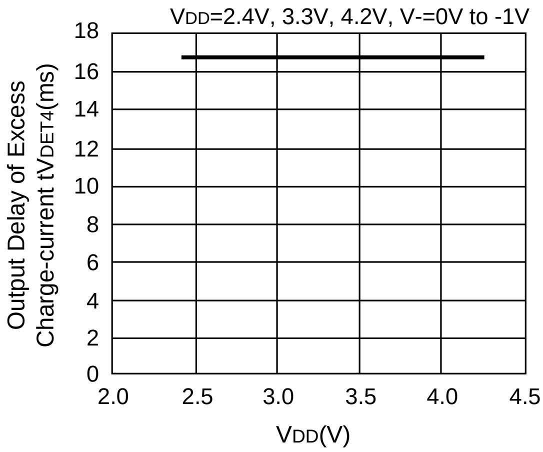
6) Output Delay for Release from Excess Discharge Current Detect vs. V_{DD}

R5426x113CA



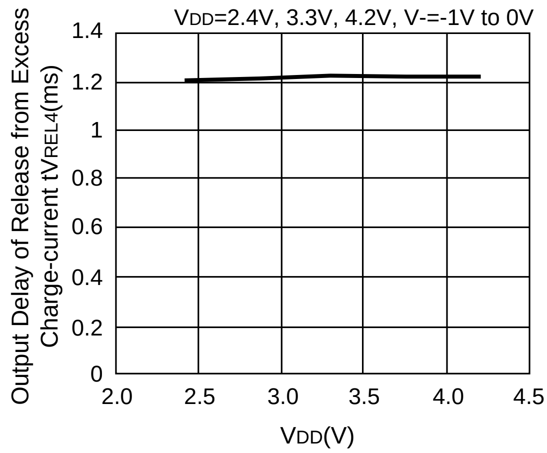
7) Delay Time for Excess Charge Current Detect vs. V_{DD}

R5426x103CA



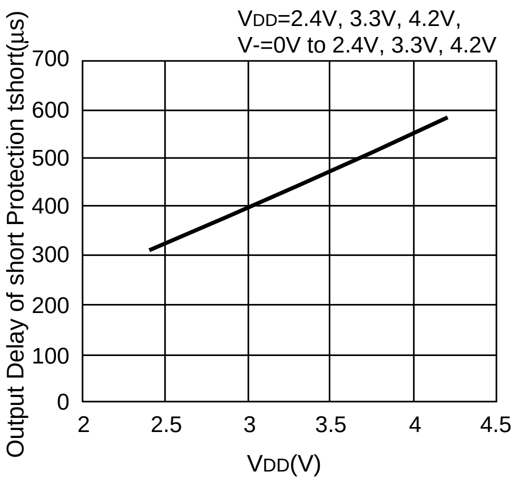
8) Delay Time for release from Excess charge current detect vs. V_{DD}

R5426x103CA



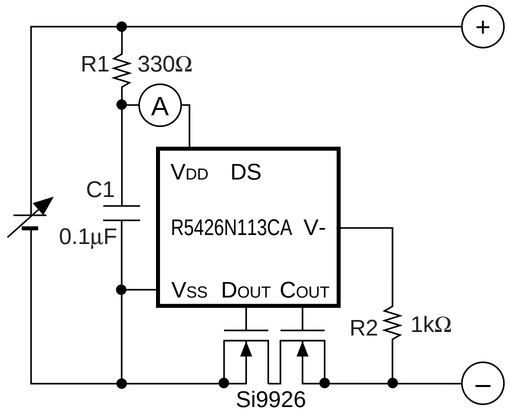
9) Output Delay for Short vs. V_{DD}

R5426x103CA

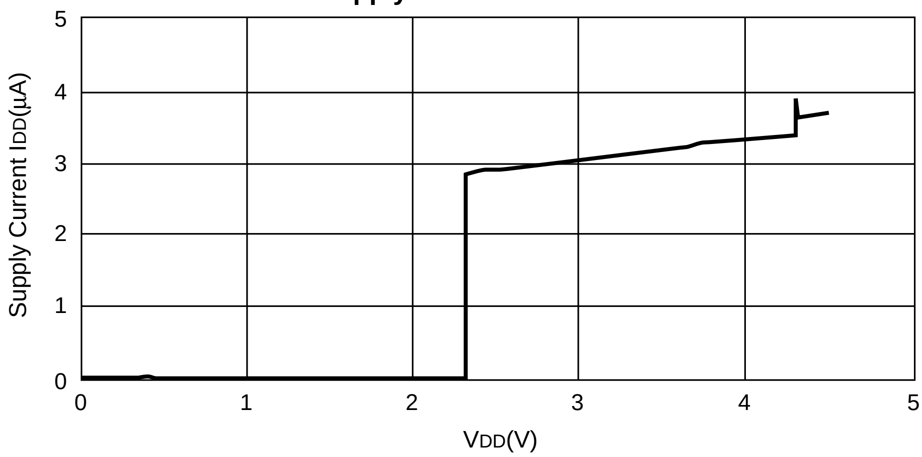


Part 3 Supply Current dependence on V_{DD}

Test Circuit

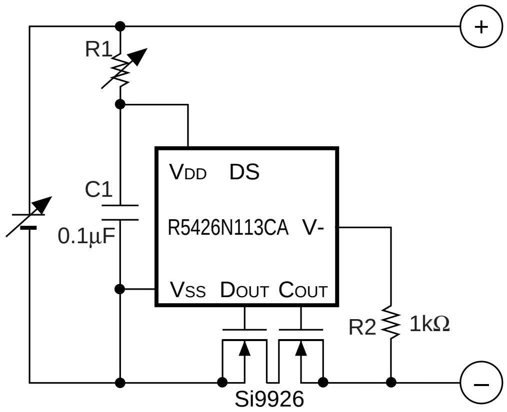


Supply Current vs. VDD

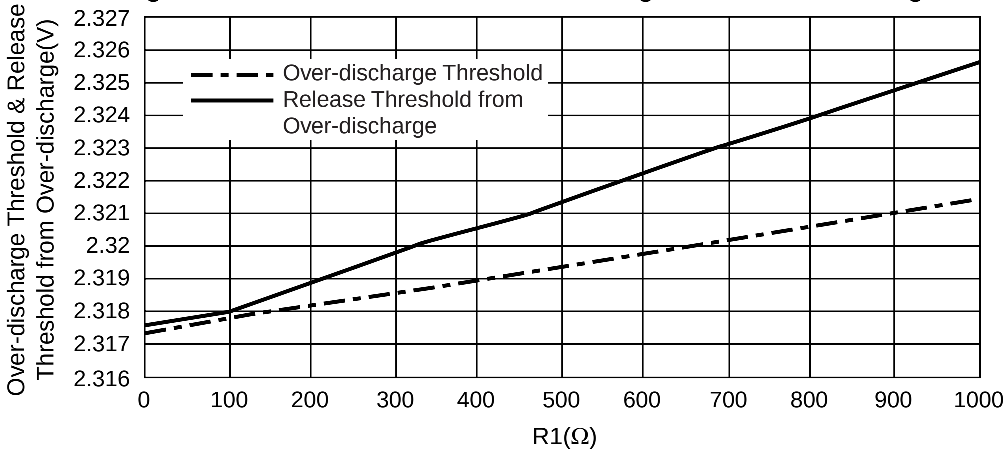


Part 4 Over-charge detector, Release voltage from Over-charge, Over-discharge detector, Release voltage from Over-discharge dependence on External Resistance value

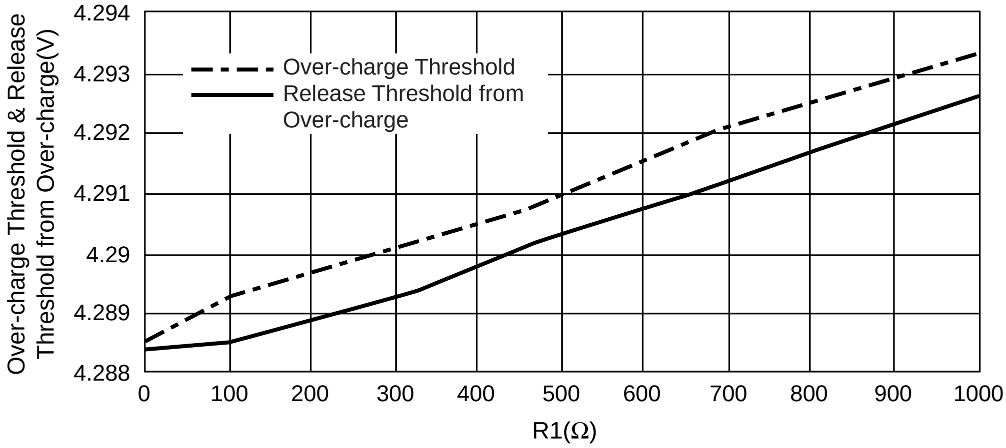
Test Circuit



Over-discharge Detector Threshold / Released Voltage from Over-discharge vs. R1

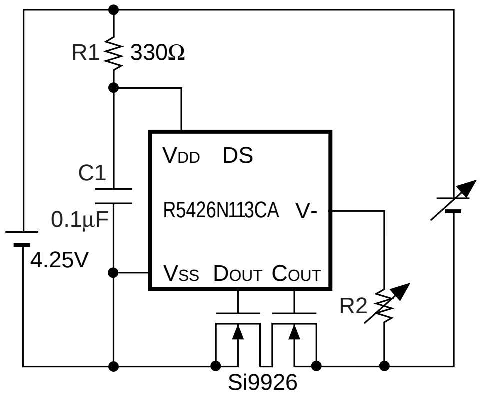


Over-charge / Released from Over-charge Threshold vs. R1



Part 5 Charger Voltage at Released from Over-discharge with a Charger dependence on R2

Test Circuit



Charger Voltage at Release from Over-discharge with a charger vs. R2